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Nuclear magnetic resonance study of anion and cation dynamics in CsSiH₃

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Abstract

In order to study the dynamical properties of cesium silanide CsSiH₃, we have measured the ¹H and ¹³³Cs nuclear magnetic resonance (NMR) spectra and spin-lattice relaxation rates in this compound over the temperature range of 5 – 354 K. The results of the ¹H NMR measurements indicate that [SiH₃]⁻ anions in CsSiH₃ retain unusually high reorientational mobility down to low temperatures. In particular, a significant narrowing of the proton NMR spectrum due to [SiH₃]⁻ reorientations is observed in the range ~ 10 – 14 K. The order-disorder ($\beta \rightarrow \alpha$) phase transition accompanied by the strong acceleration of [SiH₃]⁻ reorientations is observed above 200 K; according to the ¹H spin-lattice relaxation data, this transition appears to be gradual. For the high-temperature disordered α -phase, the activation energy for [SiH₃]⁻ reorientations is found to be 41(4) meV. The ¹³³Cs NMR results are consistent with the onset of diffusive motion of Cs⁺ cations at the frequency scale of ~10⁴ s⁻¹ above 300 K.

Keywords: A. Energy storage materials; C. Diffusion; D. Nuclear resonances

1. Introduction

Alkali-metal silanides $MSiH_3$ (M = K, Rb, Cs) consisting of M^+ cations and pyramidal [SiH₃]⁻ anions have received significant recent attention as potential hydrogenstorage materials [1-5]. These compounds can be prepared by reversible hydrogenation of Zintl phases MSi with the equilibrium hydrogen gas pressure of 0.1 MPa near 410 K [3]. Above 300 K, the crystal structure of all three $MSiH_3$ compounds is cubic (α -phase, space group $Fm\overline{3}m$) with NaCl-type arrangement of M^+ cations and orientationally disordered [SiH₃]⁻ anions. At lower temperatures, these disordered α -phases are transformed into the ordered β -phases with orthorhombic (β -KSiH₃, space group Pnma) or monoclinic (β -RbSiH₃ and β -CsSiH₃, space group $P2_1/m$) structures [3,6,7]. The corresponding entropy-driven $\alpha \leftrightarrow \beta$ phase transitions are found to be reversible, but hysteretic [7,8].

It is known that in many complex hydrides, the reorientational motion of complex anions (such as $[BH_4]^-$, $[AlH_4]^-$, $[NH_2]^-$, $[B_{12}H_{12}]^{2-}$) [9-13] strongly contributes to the balance of energies determining the thermodynamic stability of these compounds; therefore, information on the anion reorientational dynamics is important for understanding the fundamental properties of complex hydrides. The first evidence of the reorientational motion of [SiH₃]⁻ anions in alkali-metal silanides was obtained in the wide-line nuclear magnetic resonance (NMR) study [14] that revealed the narrowing of the ¹H NMR spectrum of KSiH₃ above 170 K. The motional narrowing of the ²D NMR spectrum was also observed for deuterium-substituted KSiD₃ and RbSiD₃ above 200 K [8]. Recent quasielastic neutron scattering (QENS) measurements [7,8,15,16] have shown that phase transitions from the ordered β -phases of MSiH₃ to the disordered α -phases are accompanied by the strong acceleration of anion reorientations. Typical reorientational jump rates for a-phases of all $MSiH_3$ compounds just above room temperature are of the order of 10^{12} s⁻¹. It is interesting to note that similar order-disorder phase transitions accompanied by an acceleration of anion reorientations have been found to occur in a number of complex hydrides, including the family of alkali-metal *closo*-borates with $[B_{12}H_{12}]^{2-}$ and $[B_{10}H_{10}]^{2-}$ anions [13,17-19]. The high-temperature disordered phases of lithium and sodium *closo*-borates and their derivatives exhibit extremely high Li⁺ and Na⁺ ionic conductivities [19-21], which are believed to be related [22-24] to fast anion reorientations. For alkali-metal silanides, a possible relation between anion reorientations and cation diffusion has not been studied so far.

In the present work, we use nuclear magnetic resonance measurements of ¹H and ¹³³Cs spectra and spin-lattice relaxation rates to investigate both the reorientational motion of $[SiH_3]^-$ anions and the diffusive motion of Cs^+ cations in $CsSiH_3$ over wide temperature ranges. The results of this first NMR study of $CsSiH_3$ indicate that $[SiH_3]^-$ reorientations in β -CsSiH_3 are unusually fast, and on the frequency scale of 10^5 s^{-1} they are not "frozen out" down to very low temperatures. The diffusive motion of Cs^+ cations becomes observable at the NMR frequency scale in α -CsSiH_3 above 300 K.

2. Experimental details

CsSiH₃ sample was prepared by the direct solid – gas reaction between CsSi and H₂, as described in Ref. [3]. The Zintl phase CsSi was synthesized by high-temperature annealing of a 1:1.03 mixture of cesium (99.8%, Alfa Aesar [25]) and silicon (powder, -325 mesh, Sigma Aldrich). All materials were handled in an argon-filled glovebox. The mixture was arc-weld-sealed within a stainless-steel ampule inside the glovebox. The ampule was heated to 873 K and kept at this temperature for 48 h. Then it was cooled with the rate of 0.2 K/min down to room temperature. A slight excess of silicon was added to ensure a complete reaction of the starting cesium. The resulting CsSi compound was first activated via evacuation at 473 K for 12 h and then hydrogenated at 373 K with ~5 MPa of hydrogen for 24 h. For NMR experiments, the powdered CsSiH₃ sample was flame-sealed in a glass tube under ~0.5 bar of nitrogen gas.

Low-field ¹H NMR measurements were performed on a pulse spectrometer with quadrature phase detection at the frequencies $\omega/2\pi = 28$ and 90 MHz. The magnetic field was provided by a 2.1 T iron-core Bruker magnet. A home-built multinuclear continuous-wave NMR magnetometer working in the range 0.32 - 2.15 T was used for field stabilization. For rf pulse generation, we used a home-built computer-controlled pulse programmer, a PTS frequency synthesizer (Programmed Test Sources, Inc.) and a 1 kW Kalmus wideband pulse amplifier. A probehead with the sample was placed into an Oxford Instruments CF1200 continuous-flow cryostat using nitrogen or helium as a cooling agent. The sample temperature monitored by a chromel – (Au-Fe) thermocouple was stable to ± 0.1 K. High-field ¹³³Cs NMR measurements were performed on a Bruker AVANCE III 500 spectrometer at the frequency $\omega/2\pi = 65.62$ MHz. Typical values of the $\pi/2$ pulse length were 3 - 4 µs for both ¹H and ¹³³Cs. All the NMR measurements were performed with increasing temperature and with 15 minutes stabilization time at each temperature prior to a measurement. Nuclear

spin-lattice relaxation rates were measured using the saturation – recovery method. NMR spectra were recorded by Fourier transforming the solid echo signals (pulse sequence $\pi/2_x - t - \pi/2_y$).

3. Results and discussion

3.1. ¹H NMR spectra and spin-lattice relaxation rates

The evolution of the proton NMR spectra for CsSiH₃ with temperature is shown in Fig. 1. As can be seen from this figure, the spectra exhibit a considerable narrowing with increasing temperature. Figure 2 shows the temperature dependence of the line width $\Delta_{\rm H}$ (full width at half-maximum). At low temperatures, the width of the ¹H NMR spectrum is determined by dipole-dipole interactions between static nuclear spins; this is the 'rigid-lattice' line width $\Delta_{\rm HR}$. A rough theoretical estimate of $\Delta_{\rm HR}$ can be obtained from the second moment calculations using the structural data for β -CsSiH₃ [3], see Fig. 3. The calculated 'rigid-lattice' second moment of the ¹H NMR line for β -CsSiH₃ is 5.2×10^9 s⁻². Assuming a Gaussian shape of the spectrum, this second moment should correspond to the $\Delta_{\rm HR}$ value of 27.1 kHz. The experimental $\Delta_{\rm H}$ value at T = 5 K (28.8 kHz) is close to this estimate.

With increasing temperature, the line width starts to decrease, since the onset of H jump motion leads to a partial averaging of dipole-dipole interactions. Such motional narrowing is expected to be substantial at the temperature at which the H jump rate τ^{-1} becomes nearly equal to $2\pi\Delta_{HR}$ [26]; for β -CsSiH₃, this characteristic frequency is about 1.7 $\times 10^5$ s⁻¹. As can be seen from Fig. 2, a considerable line narrowing in β -CsSiH₃ is observed already at 14 K. This means that SiH₃ groups in the cesium silanide retain high reorientational mobility down to very low temperatures. For comparison, the onset of the proton NMR line narrowing in β-KSiH₃ occurs near 170 K [14]. Recent QENS studies of *M*SiH₃ compounds [16] have shown that the reorientational SiH₃ motion in β -CsSiH₃ is much faster than in β -KSiH₃ and β -RbSiH₃. However, because of the limited energy resolution of QENS measurements, they can only probe the jump rates down to $\sim 4 \times 10^8$ s⁻¹ (for β -CsSiH₃, this low limit corresponds to the temperature of about 140 K [16]). Since NMR measurements are sensitive to much slower jump rates, they allow us to trace the reorientational motion down to lower temperatures. An Arrhenius extrapolation of the QENS results for β -CsSiH₃ [16] to the low-T region indicates that the H jump rate of 10⁵ s⁻¹ is expected to occur near 73 K. Thus, SiH₃ reorientations are not "frozen out" at the frequency

scale of 10^5 s⁻¹ down to much lower temperatures than those expected on the basis of extrapolation of the QENS data.

As can be seen from Fig. 2, in the temperature range of 100 - 200 K, the value of $\Delta_{\rm H}$ remains nearly constant. This plateau regime is related to the fact that even in the case of τ^{-1} » largely higher than $2\pi\Delta_{HR}$, a localized H motion (such as reorientational motion) leads to only partial averaging of the dipole-dipole interactions. The plateau value of $\Delta_{\rm H}$ should depend on the mechanism of reorientations. For β -CsSiH₃, the second moment of the proton NMR line is dominated by ${}^{1}H - {}^{1}H$ interactions within the same SiH₃ group (the 'intramolecular' contribution). A fast uniaxial rotation of SiH₃ group around the 3-fold symmetry axis is expected to result in a 75 % drop of this contribution to the second moment with respect to its 'rigid-lattice' value [14,27]. Assuming that the line shape is Gaussian, this corresponds to a 50 % drop of the line width. The experimental plateau value of $\Delta_{\rm H}$ for β -CsSiH₃ (~ 15 kHz) is indeed close to one-half of the low-temperature value; this is consistent with the model of uniaxial reorientations, in agreement with the QENS results for β -phases of MSiH₃ [16]. The additional decrease in the line width above 220 K (Fig. 2) can be attributed to the change in the reorientational mechanism related to the $\beta \rightarrow \alpha$ phase transition [16]. QENS data for the orientationally-disordered α -phases of MSiH₃ [7,15,16] are consistent with the reorientational mechanism in which each H atom traverses many sites on the surface of a sphere roughly centered on the Si atom. The effects of such nearly isotropic reorientational motion on $\Delta_{\rm H}$ can be estimated in the following way. Since fast isotropic rotations should average out the dipole-dipole interactions within SiH₃ groups, we have to calculate only the 'intermolecular' contribution to the second moment (between different SiH3 groups and between SiH3 groups and ¹³³Cs spins). This contribution can be roughly estimated by placing all protons in each SiH₃ group to its center (Si atom) and taking into account only the distances between centers of different groups [10]. The second moment for α -CsSiH₃ calculated using this approach is 4.1×10^8 s⁻²; for a Gaussian shape of the proton NMR line, this value corresponds to the line width of 7.6 kHz. The experimental value of $\Delta_{\rm H}$ at the high-temperature end of our measurements (8.2 kHz) is close to this estimated level.

The behavior of the proton spin-lattice relaxation rates R_1^H measured at two resonance frequencies ($\omega/2\pi = 28$ and 90 MHz) is shown in Fig. <u>34</u>. General features of the observed temperature dependence of R_1^H are typical of complex hydrides with reorienting anions [9], where the dominant relaxation mechanism is related to motional modulation of the dipoledipole interaction between nuclear spins. For this mechanism, the proton spin-lattice relaxation rate exhibits a peak at the temperature at which the reorientational jump rate τ^{-1} becomes nearly equal to the nuclear magnetic resonance frequency ω . According to the standard theory [26], in the limit of slow motion ($\omega \tau \gg 1$), R_1^H is proportional to $\omega^{-2}\tau^{-1}$, and in the limit of fast motion ($\omega \tau \ll 1$), R_1^H is proportional to τ being frequency-independent. If the temperature dependence of the jump rate τ^{-1} follows the Arrhenius law with the activation energy E_a ,

$$\tau^{-1} = \tau_0^{-1} \exp(-E_a/k_{\rm B}) , \qquad (1)$$

a plot of $\ln R_1^H$ versus T^{-1} is expected to be linear in the limits of both slow and fast motion with the slopes of $-E_a/k_B$ and E_a/k_B , respectively. As can be seen from Fig. 34, the observed behavior of R_1^H for CsSiH₃ strongly deviates from that predicted by the standard theory. First, the high-temperature slope of the $\ln R_1^H$ vs. T^{-1} peak appears to be much steeper than the low-temperature one. Second, the observed frequency dependence of R_1^H at the lowtemperature slope is considerably weaker than the predicted ω^{-2} dependence. Furthermore, there are certain deviations from the linear behavior of the $\ln R_1^H$ vs. T^{-1} plot both at high and low temperatures. The most evident reason for the unusual behavior of the proton spin-lattice relaxation rate in CsSiH₃ is the $\beta \rightarrow \alpha$ phase transition accompanied by the strong acceleration of the reorientational motion of SiH₃ groups. Because of this phase transition, the steep high-temperature slope of the $R_1^H(T)$ peak cannot be described in terms of regular thermally-activated changes in τ^{-1} ; this slope should reflect rapid changes in the H jump rate due to the phase change. It is interesting to note that in some complex hydrides the orderdisorder phase transitions lead to abrupt changes in R_1^H ; for example, the order-disorder transition in sodium closo-borate Na₂B₁₂H₁₂ near 520 K is accompanied by the two-orders-ofmagnitude drop of R_1^H over the temperature interval of 5 degrees [13]. For CsSiH₃, the relaxation rate drop is not so sharp; this may be related to specific features of the $\beta - \alpha$ phase transitions in MSiH₃ occurring via intermediate phases [8,16]. The presence of disordered α like nanodomains at temperatures much lower than the phase transition points was first reported for KSiH₃ and RbSiH₃ [8]. Because of their small size (2 - 4 nm [8]), these nanodomains may be invisible in diffraction experiments. The comprehensive QENS results for CsSiH₃ [16] are consistent with the presence of a nanostructured intermediate phase (*i*phase) with the distinct reorientational dynamics being much faster than that for the β -phase,

but slower than that for the α -phase. According to the QENS data [16], the α -, *i*-, and β -phases in CsSiH₃ can coexist over the temperature range of at least 170 – 250 K.

The complex behavior of CsSiH₃ related to the order-disorder phase transition prevents us from any attempts to parameterize the $R_1^H(T)$ data over the entire temperature range studied. Therefore, we have only tried to parameterize the $R_1^H(T)$ data at low temperatures (T < 200 K), where the β -phase is expected to be the dominant one. As noted above, the observed frequency dependence of the proton spin-lattice relaxation rate at the low-*T* slope of the $R_1^H(T)$ peak is considerably weaker than the ω^{-2} dependence. This feature is consistent with the presence of a certain distribution of H jump rates [28]. For parametrizationparameterization of our low-temperature $R_1^H(T)$ data, we have used the simplest model based on a Gaussian distribution of the activation energies [28]; for this model, the observed relaxation rate is expressed as

$$R_1^H = \int R_1^H(E_a) G(E_a, \overline{E}_a, \Delta E_a) dE_a \qquad (2)$$

Here $G(E_a, \overline{E}_a, \Delta E_a)$ is a Gaussian distribution function centered on \overline{E}_a with the dispersion ΔE_a , and $R_1^H(E_a)$ is determined by combining the standard expression that relates the relaxation rate and τ ,

$$R_1^H(E_a) = \frac{2\Delta M_{HH}\tau}{3} \left[\frac{1}{1+\omega^2\tau^2} + \frac{4}{1+4\omega^2\tau^2} \right] , \qquad (3)$$

and the Arrhenius law (Eq. (1)). The parameters of the model are the average activation energy E_a , the dispersion ΔE_a , the pre-exponential factor τ_0 and the amplitude factor ΔM_{HH} determined by the strength of the fluctuating part of dipole-dipole interaction between protons. The contribution of dipole-dipole ${}^{1}\text{H} - {}^{133}\text{Cs}$ interactions to the proton relaxation rate in CsSiH₃ can be neglected, since these interactions give only 2.6 % of the total calculated 'rigid-lattice' second moment of the ${}^{1}\text{H}$ NMR line. The model parameters have been varied to find the best fit between the model $R_{1}^{H}(T)$ and the experimental data for T < 200 K at two resonance frequencies *simultaneously*. The results of such a simultaneous fit are shown by the solid curves in Fig. <u>34</u>; the corresponding fit parameters: $E_a = 226$ (8) meV, $\Delta E_a = 78$ (4) meV, $\tau_0 = 3.7(5) \times 10^{-15}$ s, and $\Delta M_{HH} = 3.4(1) \times 10^9$ s⁻². Note that the resulting fluctuating part of the second moment, ΔM_{HH} , corresponds to ~65 % of the calculated 'rigid-lattice' second moment (see above); this is close to the expected 'intramolecular' value (75 %) [14,27] for the case of uniaxial rotation of SiH₃ groups around the 3-fold symmetry axis.

The distribution width ΔE_a resulting from the fit appears to be rather large (about one-third of \overline{E}_a). This feature may indicate the presence of an additional jump process not resolved in the spin-lattice relaxation measurements. Indeed, if the difference between two frequency scales of H jump motion is relatively small (about one order of magnitude), an additional jump process may contribute only to the low-temperature slope of the single-peak $R_1^H(T)$ dependence that mimics the typical behavior for the model with a continuous jump rate distribution. Similar behavior of $R_1^H(T)$ was reported for a number of systems with two frequency scales of H jump motion, including some Laves-phase hydrides [29] and the ordered *closo*-borate salt $Rb_2B_{10}H_{10}$ [30]. The presence of an additional jump process in the temperature range, where the β -phase is expected to be the dominant one, is also consistent with recent QENS results for $CsSiH_3$ [16]. These results indicate that the description of the elastic incoherent structure factor measured on the backscattering neutron spectrometer at 200 K in terms of the model of 3-fold SiH₃ reorientations (the only physically reasonable model for the ordered β -phase) requires an extra contribution (43 %) to the elastic peak intensity. Such a large extra contribution to the elastic peak intensity is consistent [16] with the presence of H atoms moving much faster than those in the β -phase.

The observed change in the high-temperature slope of the $\ln R_1^H$ vs. T^{-1} plot near 300 K (see Fig. 4) can be attributed to the upper boundary of the phase transition region. This interpretation implies the existence of a single α -phase of CsSiH₃ above 300 K, so that the behavior of R_1^H at T > 300 K should be governed by the regular Arrhenius temperature dependence of τ . The activation energy for H jump motion in this temperature range can be directly estimated from the proton spin-lattice relaxation data, since in the limit of fast motion (see above) R_1^H is proportional to τ . The estimate based on an Arrhenius approximation of our $R_1^H(T)$ data in the range 324 – 354 K gives the activation energy of 41(4) meV. This value is close to the activation energy for α -phase of CsSiH₃ (48(2) meV) found from QENS experiments [16].

3.2. ¹³³Cs NMR spectra and spin-lattice relaxation rates

The evolution of the ¹³³Cs NMR spectra for CsSiH₃ with temperature is shown in Fig. 5. As in the case of the proton NMR spectra, with increasing temperature we observe a considerable narrowing of the ¹³³Cs spectra accompanied by changes in their shape. The temperature dependence of the ¹³³Cs NMR line width Δ_{Cs} (full width at half-maximum) is shown in Fig. 6. In the studied temperature range of 120 – 350 K, the most pronounced drop of Δ_{Cs} is observed between 260 K and 300 K, and at T > 300 K, the line width reaches a plateau. Such a behavior is typical of the case of diffusing cations in ionic conductors (see, for example, the "steps" in ⁷Li NMR line widths in Refs. [31-33]). It should be noted, however, that in our case we should distinguish between the effects due to the reorientational H motion and the diffusive motion of Cs⁺ cations. For this purpose, we can use the results of the ¹³³Cs spin-lattice relaxation rate measurements shown in Fig. 7.

Comparison of Figs. 7 and 4 indicates that below 300 K, the behavior of the ¹³³Cs spin-lattice relaxation rate, $-R_1^{Cs}$, resembles that of R_1^H . In particular, the $R_1^{Cs}(T)$ peak is observed at nearly the same temperature as the $R_1^H(T)$ peak. Thus, the observed ¹³³Cs relaxation rate peak can be attributed to the reorientational motion of SiH₃ groups that modulates the relatively weak $^{133}Cs - {}^{1}H$ dipole-dipole interaction. This is supported by the small amplitude of the $R_1^{Cs}(T)$ peak (0.36 s⁻¹) which is two orders of magnitude lower than the amplitude of the $R_1^H(T)$ peak. Such a difference in the maximum values of the spinlattice relaxation rates is in general agreement with the estimated contributions of ${}^{133}Cs - {}^{1}H$ and ${}^{1}H - {}^{1}H$ dipole-dipole interactions to the corresponding second moments. It should be noted that reorientational jumps of SiH₃ groups are not expected to add any electric quadrupole contribution to the ¹³³Cs relaxation rate, since each reorientational jump does not change the charge configuration around Cs sites. In contrast to the case of the electric quadrupole interaction, the dipole-dipole interaction is *pairwise*, i.e., any changes in the radius vector connecting a pair of interacting nuclear spins should contribute to the nuclear spin relaxation. It can be concluded that the behavior of the ¹³³Cs spin-lattice relaxation rate below 300 K is governed by the reorientational motion of SiH₃ groups via $^{133}Cs - {}^{1}H$ dipoledipole interactions.

Above 300 K, the ¹³³Cs relaxation rate starts to increase with increasing temperature (Fig. 7). This behavior of R_1^{Cs} differs qualitatively from that of R_1^H in the same temperature range (Fig. 4); it is consistent with the onset of an additional low-frequency jump process,

such as diffusive jumps of Cs⁺ ions. It should be noted that R_1^{Cs} starts to increase at temperatures just above the characteristic "step" in the line width Δ_{Cs} (Fig. 6). This feature is typical of the onset of cation diffusive motion on the NMR frequency scale [31-33]; it corresponds to the case when the cation jump rate is higher than ~10⁴ s⁻¹ (sufficient to cause the NMR line narrowing), but is still considerably lower than ~10⁸ s⁻¹ (not reaching a new relaxation rate maximum).

5. Conclusions

The results of our proton NMR measurements indicate that [SiH₃]⁻ groups in CsSiH₃ retain unusually high reorientational mobility down to low temperatures. According to the ¹H NMR line width measurements, even at T = 14 K the jump rate of SiH₃ reorientations in CsSiH₃ is about 10⁵ s⁻¹. In agreement with recent QENS results for CsSiH₃ [16], our proton spin-lattice relaxation data are consistent with a coexistence of at least two reorientational jump processes below 200 K. The order-disorder ($\beta \rightarrow \alpha$) phase transition accompanied by the strong acceleration of SiH₃ reorientations leads to the considerable drop of the measured ¹H spin-lattice relaxation rate R_1^H ; however, this drop is not as abrupt as in the case of the order-disorder transitions in borohydrides [34] and *closo*-borates [13]. The smearing of the R_1^H "step" in the phase transition region for CsSiH₃ suggests that the order-disorder transition in this compound occurs via the formation of an intermediate phase [16]. For the high-temperature disordered α -phase of CsSiH₃, the activation energy for SiH₃ reorientations estimated from our $R_1^H(T)$ data is 41(4) meV. The ¹³³Cs NMR results are consistent with the onset of diffusive motion of Cs⁺ ions at the frequency scale of $\sim 10^4$ s⁻¹ above 300 K.

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Figure captions

Fig. 1. Evolution of the proton NMR spectrum for CsSiH₃ with temperature.

Fig. 2. Temperature dependence of the width (full width at half-maximum) of the ¹H NMR spectrum measured for CsSiH₃ at 28 MHz.

Fig. 3. Schematic view of the structure of β -CsSiH₃ (along the *c* axis). Olive spheres: Cs atoms; gray spheres: Si atoms; blue spheres: H atoms.

Fig. 4. Proton spin-lattice relaxation rates measured at 28 and 90 MHz for $CsSiH_3$ as functions of the inverse temperature. The solid lines show the simultaneous fit of the model with a Gaussian distribution of the activation energies to the data in the range 80 – 200 K.

Fig. 5. Evolution of the ¹³³Cs NMR spectrum for CsSiH₃ with temperature.

Fig. 6. Temperature dependence of the width (full width at half-maximum) of the 133 Cs NMR spectrum measured for CsSiH₃ at 65.62 MHz.

Fig. 7. 133 Cs spin-lattice relaxation rate measured at 65.62 MHz for CsSiH₃ as a function of the inverse temperature.



Fig. 1. Evolution of the proton NMR spectrum for CsSiH₃ with temperature.



Fig. 2. Temperature dependence of the width (full width at half-maximum) of the ¹H NMR spectrum measured for $CsSiH_3$ at 28 MHz.



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Fig. 5. Evolution of the ¹³³Cs NMR spectrum for CsSiH₃ with temperature.



Fig. 6. Temperature dependence of the width (full width at half-maximum) of the 133 Cs NMR spectrum measured for CsSiH₃ at 65.62 MHz.



Fig. 7. 133 Cs spin-lattice relaxation rate measured at 65.62 MHz for CsSiH₃ as a function of the inverse temperature.